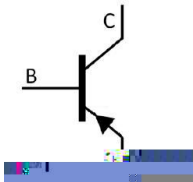


WR0<50P ММ Ё SQS æM ç s ll 1 Silicon PNP transistor in a TO-92LM Plastic Package.

Ѓ 63 Ѓ 68 Z 0BЃ 0BЃ ã 0 1 1 Ѓ 5VF495:D Ѓ ' Driver stage of 30 to 35 watts application, complementary pair with 2SC1627A.

ã 0 1 0 2 3 я 0 2 Driver stage amplifier and voltage amplifier.



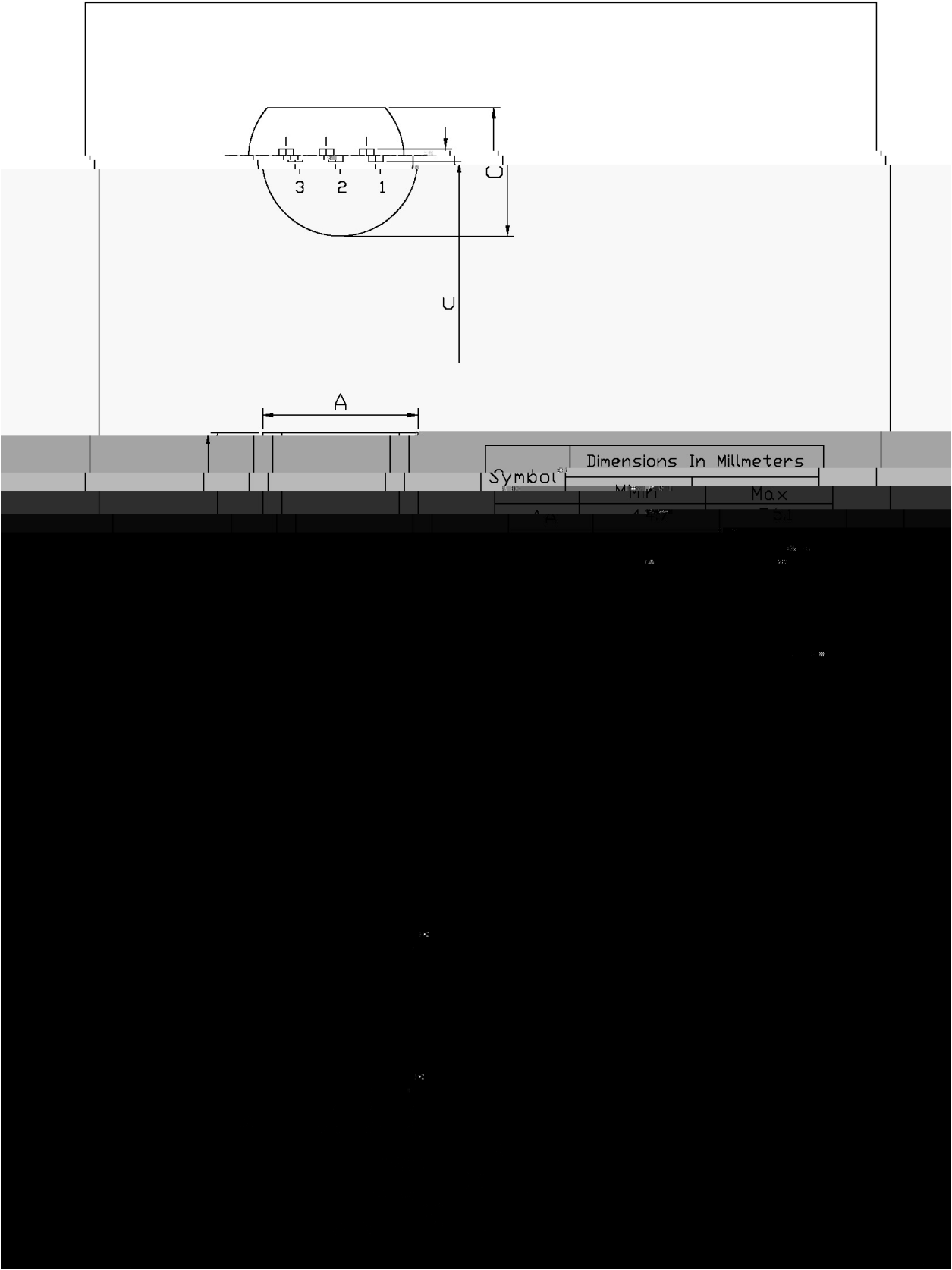
PIN1 χ Base PIN 2 χ Collector PIN 3 χ Emitter

2SA817A

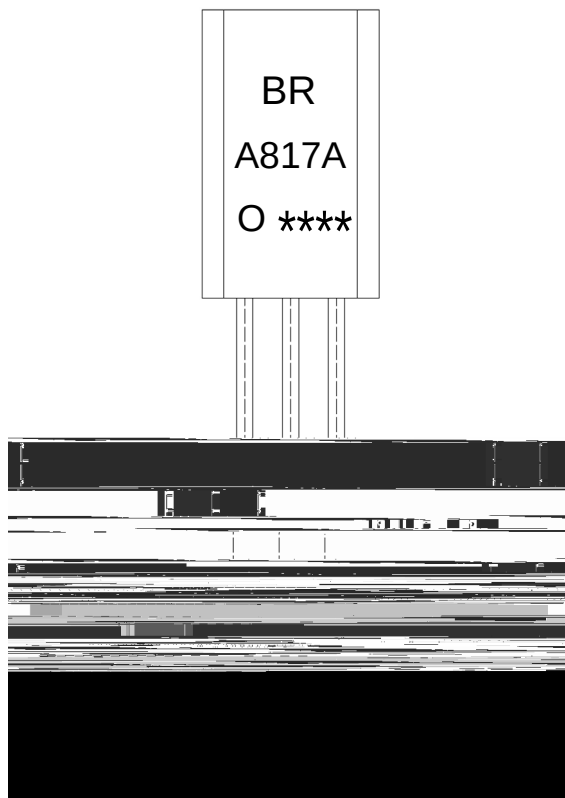
/ Package Dimensions

TO-92LM

Unit: mm



/ Marking Instructions



б " X

EU: ㄣ 3^N Γᄡ

D;4:D X ㄣ 3^N Γᄡ

R: ㄣ k_{IH}⁶ Γᄡ

---- X ㄣ 1 F ᄡ^N Γᄡ 1 ㄣ 1 F ᄡ^N Ψ ᄡ

Note:

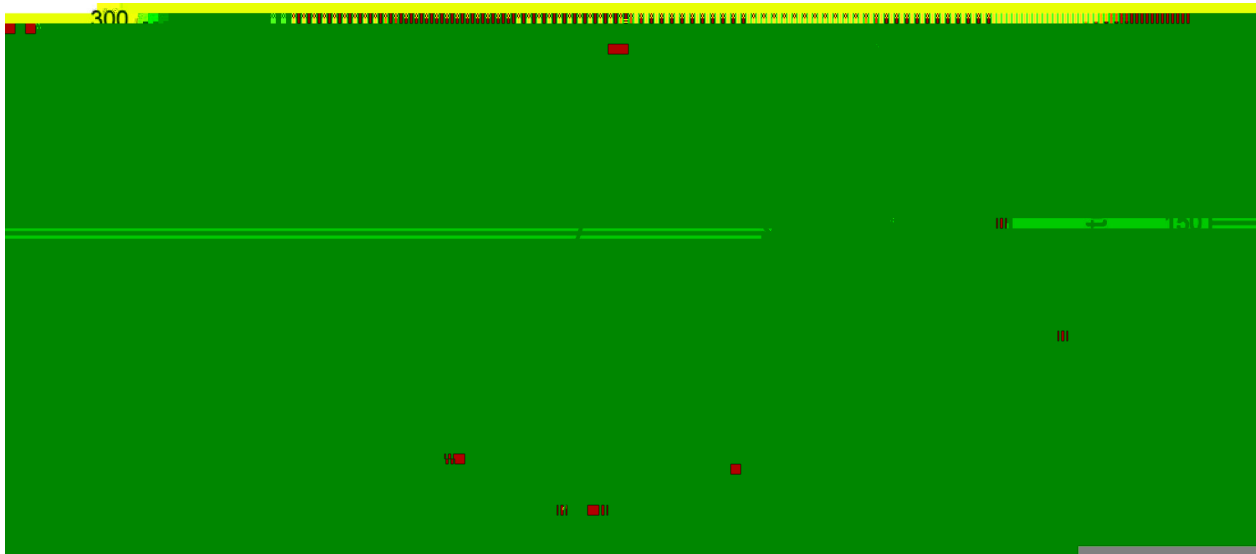
BR: Company Code.

A817A: Product Type.

O: h_{FE} Classifications Symbol

****: Lot No. Code,code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



б " X

1. 1. Preheating: 25~150 °C, Time: 60~90sec;
2. 2. Peak Temp.: 255 °C, Duration: 5~10sec;
3. 3. Cooling Speed: 2~10 °C/sec.

Note:

1. Preheating: 25~150 °C, Time: 60~90sec.
2. Peak Temp.: 255 °C, Duration: 5~10sec.
3. Cooling Speed: 2~10 °C/sec.

/ Resistance to Soldering Heat Test Conditions

□ °C 270 °C ± 5 °C, Time: 10 ± 1 sec.

Temp.: 270 °C ± 5 °C

Time: 10 ± 1 sec

AW t) 0.5 sec CY 0.1 sec

131.44 295146 0 Tw 1 T4ca19 01 -5s/Bag1.8P5 5.9517]TJ /TT Dim0.66657 -1-2220 TD 0 Tc 111a343 TD.127 1 T